



Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638
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Designer's Data Sheet

Part Number/Ordering Information 1/

SDA345

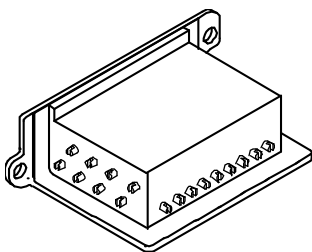
— Screening 2/

— = Not Screened

TX = TX Level

TXV = TXV

S = S Level



SDA345

ULTRA FAST RECOVERY HIGH VOLTAGE ASSEMBLY

Up To 18KV @ 250mA

125KHz Operating Frequency

FEATURES:

- Designed For Use With High Voltage Switching Power Supplies
- Discretes and Assemblies Screened to TX, TXV, or S Level
- High Reverse Transient Energy Capabilities
- Void Free, Hermetically Sealed, Metallurgically Bonded Discretes
- Single Junction Discretes Provide Superior Thermal Properties Than Designs Using Multi-junction Discretes
- Isolated Aluminum Heat Sink with Special Epoxy Encapsulation Provides Superior Power Dissipation
- All Internal Devices are Matched & Selected
- Unique Construction Techniques Guarantee 100% Corona Free Operation
- Consult Factory for Higher Voltages and Currents and Alternate Bridge Configurations

MAXIMUM RATINGS PER LEG

ELECTRICAL CHARACTERISTICS PER LEG

Rating ^{1/}	Symbol	Value	Unit	Characteristic ^{1/}	Symbol	Value	Unit
Peak Repetitive Reverse Voltage and DC Blocking Voltage	VRM(rep) V _r	3,000	Volts	Max. Full Cycle Forward Voltage Drop, Averaged Over Full Cycle ^{6/}	V _F (AV)	2.85	V _{dc}
RMS Reverse Voltage	V _r	2,100	Volts	Max. Instantaneous Forward Voltage Drop ^{2/}	V _F	5.7	V _{dc}
Half Wave Rectified Forward Current Averaged Over Full Cycle ^{2/}	I _o	1	Amps	Max. Full Cycle Leakage Current Averaged Over Full Cycle ^{8/}	I _R (AV)	100	μA _{dc}
Peak Repetitive Forward Current ^{3/}	IFM(rep)	6	Amps	Max. Reverse Leakage Current ^{9/}	I _R	5	μA _{dc}
Peak Surge Current ^{4/}	IFM(surge)	25	Amps	Max. Junction Capacitance ^{10/}	C _J	4	pf
Operating & Storage Temperature	T _J , T _{stg}	-55 to +125	°C				
Reverse Recovery Time ^{5/}	t _{rr}	60	ns				

NOTES:

^{1/} Unless Otherwise Specified, All Electrical Characteristics @25°C.

^{2/} Resistive Load, 50Hz, Sine Wave, TC=25°C.

^{3/} TC=55°C, 8.3ms Pulse, Allow Junction to Reach Equilibrium Between Pulses.

^{4/} TC=55°C, 8.3ms Pulse, Superimposed on Rated Current at Rated Voltage.

^{5/} Recovery Conditions: I_F = 0.5 Amp, I_R = 1.0 Amp rec. to .25 Amp, tested on each individual diode before assembly.

^{6/} I_O (MAX), 60Hz, Square Wave, TC = 55°C.

^{7/} I_F = 1 A_{dc}, TC = 25°C, 300 μs Pulse.

^{8/} Rated V_R, 60Hz, Square Wave, TC = 100°C.

^{9/} Rated V_R, TC = 25°C.

^{10/} V_R = 100V, TC = 25°C.

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RA0072A

DOC



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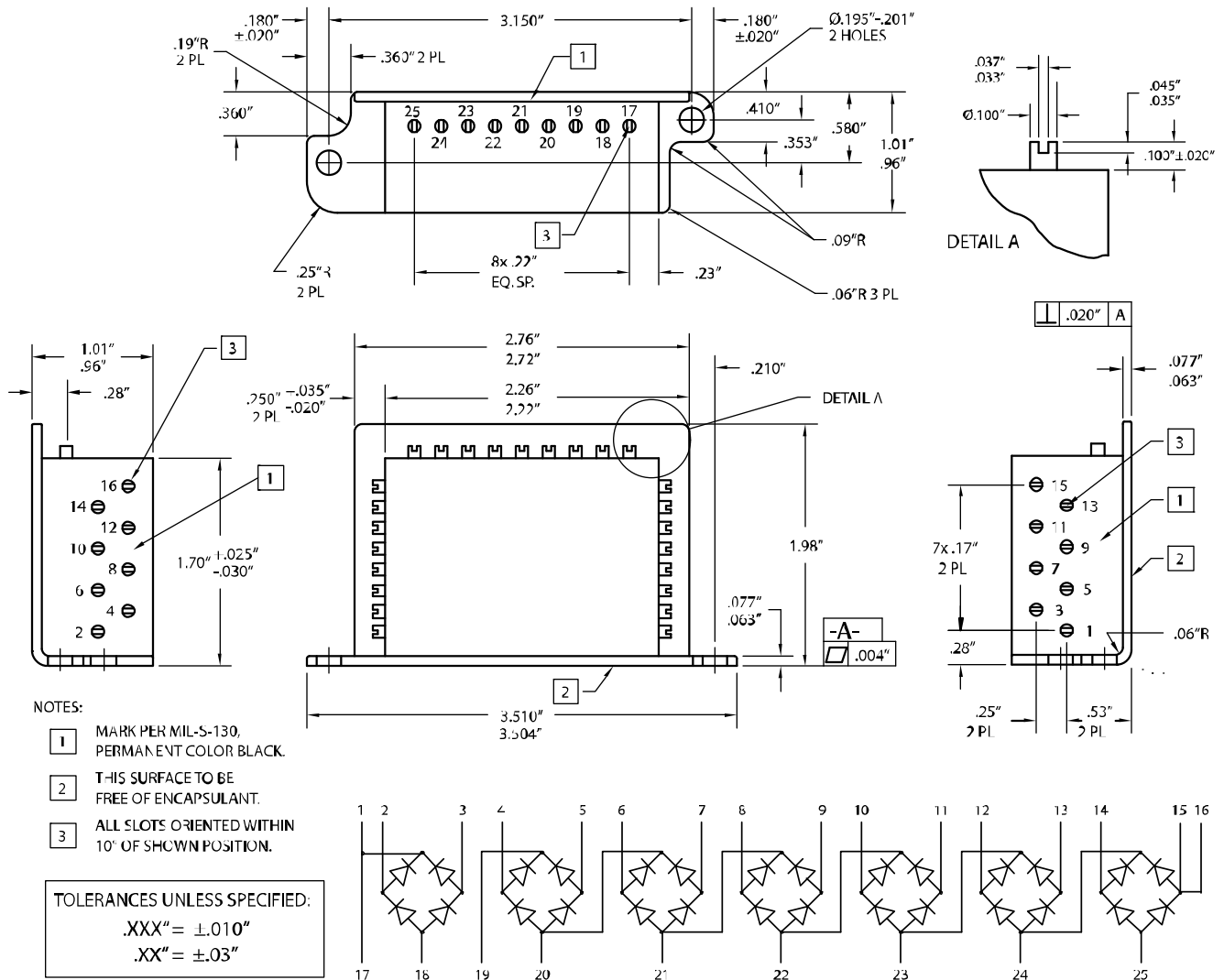
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SDA345

SDA345 OUTLINE and SCHEMATIC DRAWING:



*For information on curves, contact the Factory Representative for Engineering Assistance.